# **MOS FET Relays**

G3VM-61G1

### New MOS FET Relay Designed for Switching Minute Signals and Analog Signals

- Upgraded G3VM-S1 Series.
- Continuous load current of 400 mA.
- Dielectric strength of 1,500 Vrms between I/O.

#### **■** Application Examples

- Broadband systems
- · Data loggers
- Measurement devices
- · Amusement machines



**Note:** The actual product is marked differently from the image shown here.

#### **■**List of Models

Contact form	Terminals	Load voltage (peak value)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting	60 VAC	G3VM-61G1	100	
	terminals		G3VM-61G1(TR)		2,500

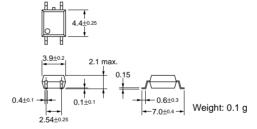
#### **■** Dimensions

Note: All units are in millimeters unless otherwise indicated.

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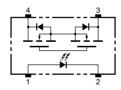


**Note:** The actual product is marked differently from the image shown here.



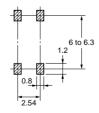
#### ■ Terminal Arrangement/Internal Connections (Top View)

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## ■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

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Note:

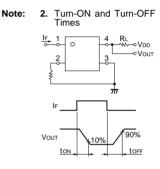
#### ■ Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current	I <sub>F</sub>	50	mA	
	Repetitive peak LED forward current	I <sub>FP</sub>	1	Α	100 μs pulses, 100 pps
	LED forward current reduction rate	Δ I <sub>F</sub> /°C	-0.5	mA/°C	Ta ≥ 25°C
	LED reverse voltage	$V_R$	5	V	
	Connection temperature	Tj	125	°C	
Output	Output dielectric strength	$V_{OFF}$	60	V	
	Continuous load current	I <sub>O</sub>	400	mA	
	ON current reduction rate	Δ I <sub>ON</sub> /°C	-4.0	mA/°C	Ta ≥ 25°C
	Connection temperature	Tj	125	°C	
	ic strength between input and See note 1.)	V <sub>I-O</sub>	1,500	Vrms	AC for 1 min
Operating temperature		Ta	-40 to +85	°C	With no icing or condensation
Storage temperature		T <sub>stg</sub>	-55 to +125	°C	With no icing or condensation
Soldering temperature (10 s)			260	°C	10 s

The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

## **■** Electrical Characteristics (Ta = 25°C)

ltem		Symbol	Mini- mum	Typical	Maxi- mum	Unit	Measurement conditions	
Input	LED forward voltage	$V_{F}$	1.0	1.15	1.3	V	I <sub>F</sub> = 10 mA	
	Reverse current	I <sub>R</sub>			10	μА	V <sub>R</sub> = 5 V	
	Capacity between terminals	C <sub>T</sub>		30		pF	V = 0, f = 1 MHz	
	Trigger LED forward current	I <sub>FT</sub>		1.6	3	mA	I <sub>O</sub> = 400 mA	
Output	Maximum resistance with output ON	R <sub>ON</sub>		1	2	Ω	I <sub>F</sub> = 5 mA, I <sub>O</sub> = 400 mA	
	Current leakage when the relay is open	I <sub>LEAK</sub>			1.0	μА	V <sub>OFF</sub> = 60 V	
Capacity	Capacity between I/O terminals			0.8		pF	f = 1 MHz, Vs = 0 V	
Insulation resistance		R <sub>I-O</sub>	1,000			ΜΩ	$V_{I-O}$ = 500 VDC, RoH $\leq$ 60%	
Turn-ON	Turn-ON time			0.8	2.0	ms	$I_F = 5 \text{ mA}, R_L = 200 \Omega, V_{DD} = 20 \text{ V (See note 2.)}$	
Turn-OFF time		tOFF		0.1	0.5	ms		



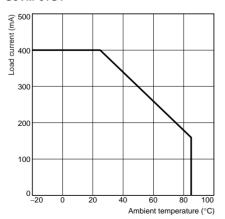
## **■**Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Output dielectric strength	$V_{DD}$			48	V
Operating LED forward current	I <sub>F</sub>	5	7.5	25	mA
Continuous load current	I <sub>O</sub>			400	mA
Operating temperature	Ta	- 20		65	°C

#### **■** Engineering Data

## Load Current vs. Ambient Temperature G3VM-61G1



#### **■** Safety Precautions

Refer to page 6 for precautions common to all G3VM models.